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FDS6890A

Dual N-Channel 2.5V Specified PowerTrench™ MOSFET

General Description

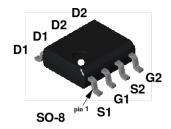
These N-Channel 2.5V specified MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize the on-state resistance and yet maintain low gate charge for superior switching performance.

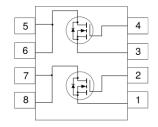
Applications

- DC/DC converter
- Motor drives

Features

- 7.5 A, 20 V. $R_{DS(ON)} = 0.018~\Omega~$ @ $V_{GS} = 4.5~V$ $R_{DS(ON)} = 0.022~\Omega~$ @ $V_{GS} = 2.5~V.$
- Low gate charge (23nC typical).
- Fast switching speed.
- High performance trench technology for extremely low $R_{\scriptscriptstyle DS(ON)}$.
- High power and current handling capability.





Absolute Maximum Ratings TA=25°C unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		20	V
V _{GSS}	Gate-Source Voltage		±8	V
I _D	Drain Current - Continuous	(Note 1a)	7.5	A
	- Pulsed		20	
P _D	Power Dissipation for Dual Operation		2.0	W
	Power Dissipation for Single Operation	(Note 1a)	1.6	7
		(Note 1b)	1.0	7
		(Note 1c)	0.9	7
T _J , T _{stg}	Operating and Storage Junction Temperature Range		-55 to +150	°C

Thermal Characteristics

R_{eJA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
R _e JC	Thermal Resistance, Junction-to-Case	(Note 1)	40	°C/W
			90	

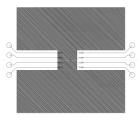
Package Marking and Ordering Information

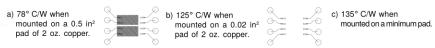
Device Marking	Device	Reel Size	Tape Width	Quantity
FDS6890A FDS6890A		13	12mm	2500 units

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics			,	,	
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	20			V
ΔBV _{DSS} ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		14		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 16 V, V _{GS} = 0 V			1	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 8 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -8 V, V _{DS} = 0 V			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.5	0.8	1.5	V
ΔV _{GS(th)} ΔΤ _J	Gate Threshold Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		-3.5		mV/°C
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 7.5 \text{ A}$ $V_{GS} = 4.5 \text{ V}, I_D = 7.5 \text{ A}, T_J = 125 ^{\circ}\text{C}$ $V_{GS} = 2.5 \text{ V}, I_D = 6.5 \text{ A}$		0.013 0.021 0.016	0.018 0.034 0.022	Ω
I _{D(on)}	On-State Drain Current	V _{GS} = 10 V, V _{DS} = 5 V	20			Α
g FS	Forward Transconductance	V _{DS} = 5 V, I _D = 7.5 A		35		S
Dynamic	Characteristics	•				
C _{iss}	Input Capacitance	V _{DS} = 10 V, V _{GS} = 0 V,		2130		pF
Coss	Output Capacitance	f = 1.0 MHz		545		pF
C _{rss}	Reverse Transfer Capacitance	1		270		pF
Switchir	ng Characteristics (Note 2)					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 10 V, I _D = 1 A,		13	24	ns
t _r	Turn-On Rise Time	$V_{GS} = 4.5 \text{ V}, R_{GEN} = 6 \Omega$		26	42	ns
t _{d(off)}	Turn-Off Delay Time	1		65	90	ns
t _f	Turn-Off Fall Time	1		23	37	ns
Qg	Total Gate Charge	V _{DS} = 10 V, I _D = 7.5 A,		23	32	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = 4.5 V$,		3.2		nC
Q _{gd}	Gate-Drain Charge	1		4.4		nC
Drain-Sc	ource Diode Characteristics	and Maximum Ratings				
I _S	Maximum Continuous Drain-Source				1.3	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 1.3 A (Note 2)		0.65	1.2	V

Notes:

R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{BJC} is guaranteed by design while R_{BCA} is determined by the user's board design.







Scale 1 : 1 on letter size paper

Typical Characteristics (continued)

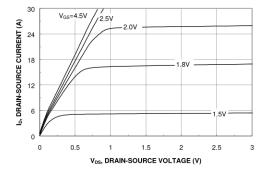


Figure 1. On-Region Characteristics.

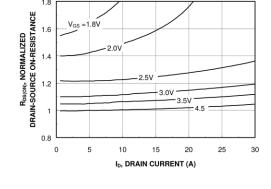


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

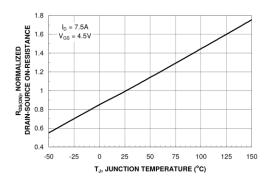


Figure 3. On-Resistance Variation with Temperature.

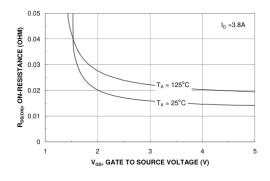


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

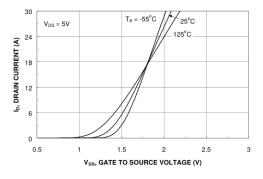


Figure 5. Transfer Characteristics.

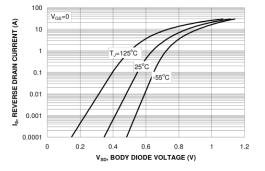
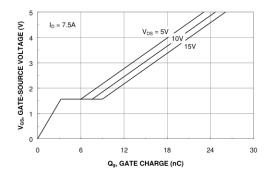


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics (continued)



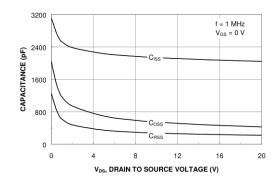
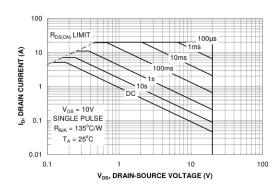


Figure 7. Gate Charge Characteristics.





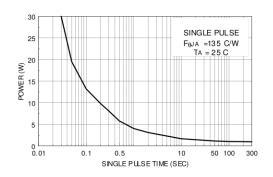


Figure 9. Maximum Safe Operating Area.

Figure 10. Single Pulse Maximum Power Dissipation.

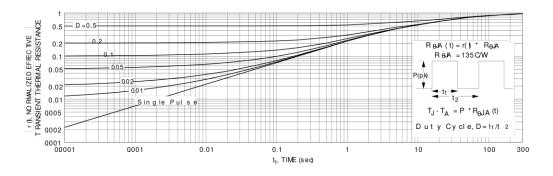


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1c. Transient themal response will change depending on the circuit board design.

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